

Silicon Germanium (SiGe) Substrates In Stock

Silicon Germanium (SiGe) strained silicon for research/production.

SOUTH BOSTON, MASSACHUSETTS, UNITED STATES, April 1, 2019 /EINPresswire.com/ -- We have the following [Silicon Germanium](#) Substrates in stock for research and production.

Pls see below for the [SiGe](#) on Si wafer general specification, Mini order qty. 10~15pcs, price depends on customer's requirements.

Substrate Description	Prime, Single crystal Silicon
Diameter	100mm, 150mm, 200mm
Thickness	Semi-Standard
Resistivity	1-100 Ohm.cm
Type	P-type/N-type



Why buy substrates in volume if you don't have to? Buy as few as one substrate and save!"

Christian J. Baker

Polish	One side epi polished (100)
Orientation	
Epitaxial layer	
Composition	SixGe1-x
Thickness	Upon-request
Dopant	None
Stress state	Strained/Relaxed

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